NSN 5962-01-068-9594

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-068-9594

Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inches and 0.310 inches	
Body Height:	
Between 0.140 inches and 0.185 inches	
Maximum Power Dissipation Rating:	
794.0 milliwatts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
Features Provided:	
Hermetically sealed and monolithic and positive outputs and bipolar and schottky and programmable and 3-state output and w/d	ecoded
output and w/enable and w/storage and w/disable	
Inclosure Material:	
Ceramic and glass	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
10 input	
Case Outline Source And Designator:	
D-2 mil-m-38510	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteristic:	
5.5 volts power source	
Time Rating Per Chacteristic:	
85.00 nanoseconds propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to lo	ow level
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Test Data Document:	
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in spec	cification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certa	ain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).	

Terminal Type And Quantity:

16 printed circuit

Shalf Life

Specification Data:

81349-mil-m-38510/204 government specification

NSN 5962-01-068-9594

Memory Microcircuit - Page 2 of 2

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

